

2004

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Guo, Shangping; Wu, Feng; and Albin, Sacharia, "Photonic Band Gap Analysis Using Finite-Difference Frequency-Domain Method" (2004). *Electrical & Computer Engineering Faculty Publications*. 175.
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Original Publication Citation

Guo, S., Wu, F., Albin, S., & Rogowski, R. S. (2004). Photonic band gap analysis using finite-difference frequency-domain method. *Optics Express*, 12(8), 1741-1746. doi:10.1364/OPEX.12.001741

Photonic band gap analysis using finite-difference frequency-domain method

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Abstract: A finite-difference frequency-domain (FDFD) method is applied for photonic band gap calculations. The Maxwell's equations under generalized coordinates are solved for both orthogonal and non-orthogonal lattice geometries. Complete and accurate band gap information is obtained by using this FDFD approach. Numerical results for 2D TE/TM modes in square and triangular lattices are in excellent agreements with results from plane wave method (PWM). The accuracy, convergence and computation time of this method are also discussed.

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OCIS code: (350.3950) Micro-optics (260.2110) Electromagnetic theory

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1. Introduction

Photonic band gap materials and devices have been under intense research for over a decade following the seminal papers [1-2]. There are several methods for band structure analysis, such as the plane wave method (PWM) [3-5] and the FDTD [6-9] method. The PWM is able to provide complete and accurate information. However, the algorithm complexity is $O(N^3)$ and the computation is heavy for large problems. The order-N method based on FDTD can effectively reduce computation. It solves the Maxwell's equations within the unit cell in time-domain by applying an initial field that covers all the possible symmetries; the eigen-modes are identified as the spectral peaks from the Fourier transform of the time-variant fields. The drawback of this method is that the accuracy depends on the number of iterations in time. There is also a possibility of losing true eigen-mode if the corresponding peak is too small, or resolution is too low. Moreover, spurious modes may arise from spectral noise. The FDFD method has been proposed for optical waveguide analysis [10-12], which is accurate and stable. In this paper, we show that this technique can be applied in photonic band gap analysis and we note that an FDFD approach using Helmholtz equation has been shown in [13]. First we describe the derivation of the FDFD algorithm under generalized coordinate system and then apply the algorithm on 2D photonic crystals with two different geometries. The accuracy, convergence, and computation time in the FDFD method are compared with those of PWM.

2. Theory

We consider nonconductive materials under generalized coordinates denoted by three unit basis vectors $u_q(x,y,z)$ ($q=1,2,3$). The Maxwell's curl equations in complex form can be expressed as [9, 15]:

$$\nabla_q \times \hat{H} = jk_0 \hat{\epsilon}(r) \hat{E} \quad \nabla_q \times \hat{E} = -jk_0 \hat{\mu}(r) \hat{H}, \quad (1)$$

$$\text{and the renormalized fields are: } \hat{E}_i = Q_i \sqrt{\epsilon_0/\mu_0} E_i \quad \hat{H}_i = Q_i H_i, \quad (2)$$

where k_0 is the wave vector in free space, Q_i 's are the grid size along each direction. The $\hat{\epsilon}$ and $\hat{\mu}$ are respectively the effective relative permittivity and permeability constants which are 3x3 tensors under the generalized coordinate system:

$$\hat{\epsilon}_{ij}(r) = \epsilon_{ri}(r) g_{ij} |u_1 \cdot u_2 \times u_3| \frac{Q_1 Q_2 Q_3}{Q_i Q_j Q_0} \quad \hat{\mu}_{ij}(r) = \mu_{ri}(r) g_{ij} |u_1 \cdot u_2 \times u_3| \frac{Q_1 Q_2 Q_3}{Q_i Q_j Q_0}. \quad (3)$$

Q_0 is a constant introduced to be roughly equal to Q_i 's; $|u_1 \cdot u_2 \times u_3|$ is the volume of the unit cell, ϵ_{ri} (μ_{ri}) is the relative dielectric constant (the relative permeability constant) at the position where the electric field \hat{E}_i (the magnetic field \hat{H}_i) is located. g is the metric tensor that can be obtained using the three unit vectors,

$$g^{-1} = \begin{bmatrix} u_1 \cdot u_1 & u_1 \cdot u_2 & u_1 \cdot u_3 \\ u_2 \cdot u_1 & u_2 \cdot u_2 & u_2 \cdot u_3 \\ u_3 \cdot u_1 & u_3 \cdot u_2 & u_3 \cdot u_3 \end{bmatrix} \quad (4)$$

and the length in generalized coordinate can be calculated using:

$$|r^2| = \vec{r}^T [g^{-1}] \vec{r}. \quad (5)$$

We use Yee's mesh [14] and finite difference to replace the derivatives in Maxwell's curl equations [9, 15] and formulate them in matrix form using the approach described in [10]:

$$jk_0 \begin{bmatrix} \hat{E}_1 \\ \hat{E}_2 \\ \hat{E}_3 \end{bmatrix} = \begin{bmatrix} \epsilon_{11}^{-1} & \epsilon_{12}^{-1} & \epsilon_{13}^{-1} \\ \epsilon_{21}^{-1} & \epsilon_{22}^{-1} & \epsilon_{23}^{-1} \\ \epsilon_{31}^{-1} & \epsilon_{32}^{-1} & \epsilon_{33}^{-1} \end{bmatrix} \begin{bmatrix} 0 & -U_3 & U_2 \\ U_3 & 0 & -U_1 \\ -U_2 & U_1 & 0 \end{bmatrix} \begin{bmatrix} \hat{H}_1 \\ \hat{H}_2 \\ \hat{H}_3 \end{bmatrix}, \quad (6)$$

$$-jk_0 \begin{bmatrix} \hat{H}_1 \\ \hat{H}_2 \\ \hat{H}_3 \end{bmatrix} = \begin{bmatrix} \mu_{11}^{-1} & \mu_{12}^{-1} & \mu_{13}^{-1} \\ \mu_{21}^{-1} & \mu_{22}^{-1} & \mu_{23}^{-1} \\ \mu_{31}^{-1} & \mu_{32}^{-1} & \mu_{33}^{-1} \end{bmatrix} \begin{bmatrix} 0 & -V_3 & V_2 \\ V_3 & 0 & -V_1 \\ -V_2 & V_1 & 0 \end{bmatrix} \begin{bmatrix} \hat{E}_1 \\ \hat{E}_2 \\ \hat{E}_3 \end{bmatrix}, \quad (7)$$

where U_i and V_i are coefficient matrices formed according to the boundary conditions, and they are proportional to $1/Q_i$.

An eigen-value problem in frequency-domain is formed for either \hat{E} or \hat{H} by eliminating \hat{H} or \hat{E} in Eqs. (6-7). For a given wave vector k , all the referred components outside the unit cell boundary can be obtained using Bloch's periodic boundary condition:

$$\hat{H}(r + R_l) = \exp(ik \cdot R_l) \hat{H}(r) \quad \hat{E}(r + R_l) = \exp(ik \cdot R_l) \hat{E}(r), \quad (8)$$

where R_l can be an arbitrary lattice vector, and here it is limited in the unit cell or supercell.

Two-dimensional cases

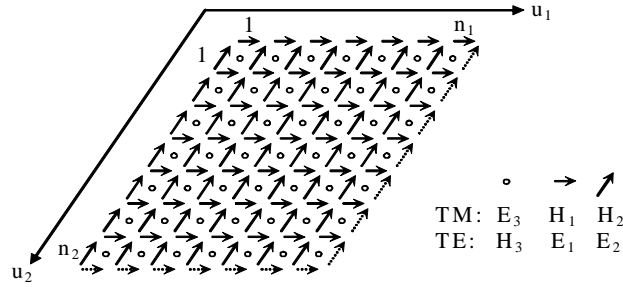


Fig. 1. Yee's 2D mesh in general coordinates. The dotted components are at the boundaries.

A 2D Yee's mesh under generalized coordinate system is shown in Fig. 1 for both TE and TM modes. E and H are arranged along two basis vectors u_1 and u_2 ; u_3 is coincident with the z direction. Since Q_3 is infinite, U_3 and V_3 in the equation (6-7) are zero, and simple eigen-equations can be obtained. The lattice vector R_l in Eq. (8) is chosen to be $a_q u_q$, and a_q is the dimension of the unit cell or supercell along direction q .

For TM modes, the eigen-equation is shown as follows:

$$k_0^2 \hat{E}_z = \epsilon_{33}^{-1} \left\{ U_1 (\mu_{21}^{-1} V_2 - \mu_{22}^{-1} V_1) - U_2 (\mu_{11}^{-1} V_2 - \mu_{12}^{-1} V_1) \right\} \hat{E}_z. \quad (9)$$

The fields E and H in the two dimensional grids are arranged row by row into column vectors. Subsequently the Bloch boundary conditions are applied to get the matrices U and V:

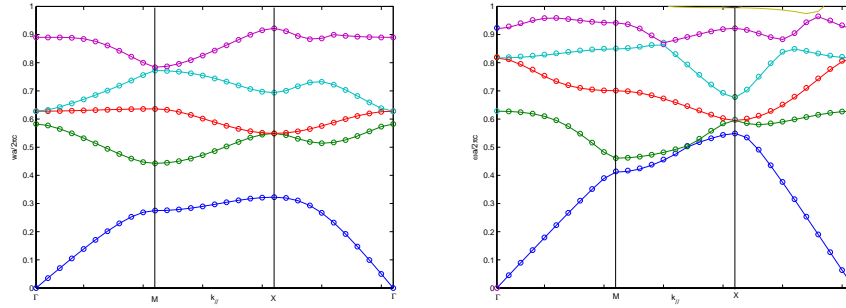


Fig. 2. The band structure for a 2D square lattice by FDFD (o) and PWM (-). 441 plane waves are used for PWM and mesh resolution is $a/80$ for FDFD. Left: TM mode, Right: TE mode.

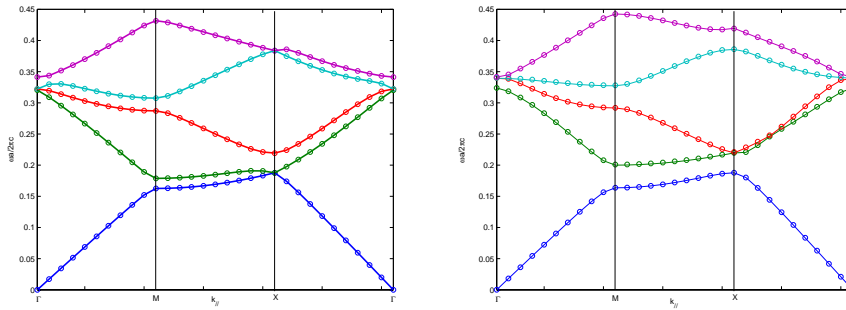


Fig. 3. The calculated band structure of a triangular lattice by FDFD (o) and PWM (-). 441 plane waves are used for PWM and mesh resolution is $a/80$ for FDFD. Left: TM, Right: TE.

The TE/TM band gap for 2D square lattice and triangular lattice of the above examples are shown in Fig. 2 and Fig. 3 respectively. The FDFD results are indicated by ‘o’ and PWM results are plotted as solid lines. The results from the two methods show excellent agreements.

In Table 1 we list the first five bands at $k=0$ for the 2D triangular lattice shown above using the two methods in order to compare their accuracy and computation time. The computation time is measured on a 2.4GHz mobile Celeron® notebook with 256MB memory. From the Table we see that FDFD can reach the same accuracy as PWM in a shorter time.

Table 1. Eigen-frequencies for the first five bands of TE wave ($k=0$) for a triangular lattice with air holes in dielectric materials.

Band No:	1	2	3	4	5	Time (s)
PWM 441 ¹	0	0.3240	0.3398	0.3399	0.3414	47.84
PWM 625 ¹	0	0.3240	0.3399	0.3399	0.3414	105.66
PWM 961 ¹	0	0.3240	0.3400	0.3400	0.3414	256.36
FDFD 40 ²	0	0.3237	0.3395	0.3400	0.3418	3.29
FDFD 80 ²	0	0.3240	0.3400	0.3402	0.3416	11.68
FDFD 120 ²	0	0.3240	0.3400	0.3402	0.3415	33.18
FDFD 160 ²	0	0.3240	0.3401	0.3402	0.3414	86.09

1: The number of plane waves, 2: the number of grids along each direction.

A convergence curve for the eigen-frequency of band 5 at $k=0$ is shown in Fig. 4 versus the number of grids used along each direction. The computation time is also presented in the figure. The eigen-values converge to the accurate value at a moderate mesh size, for example, $a/80$. The computation time is highly dependent on the memory available on the computer.

When the unit cell or supercell has symmetry properties, computation time could be saved by using part of the unit cell under proper boundary conditions [18].

Next, we show a defect mode analysis using FDFD for the 2D square lattice of alumina rods in air as in the first example. A 5x5 supercell is selected and 200 grids are used along each direction. In this case, only the defect frequency is of interest since the band gap information is already known. Therefore we only have to find a certain number of eigen-frequencies of interest and the computation time is effectively reduced. The eigen-frequency obtained by FDFD is 0.3930. The mode field is shown in Fig. 5. Both results agree well with those by PWM and FDTD [16-17].

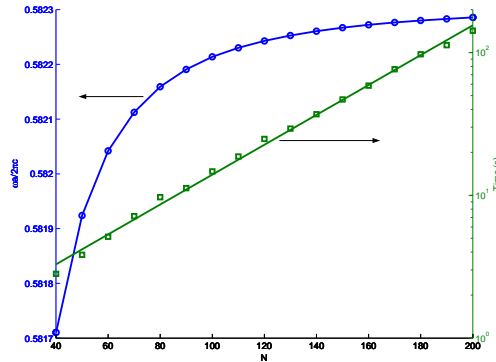


Fig. 4. The convergence of eigen-frequency (the 5th band at $k=0$) and the computation time vs. the number of grids along each direction.

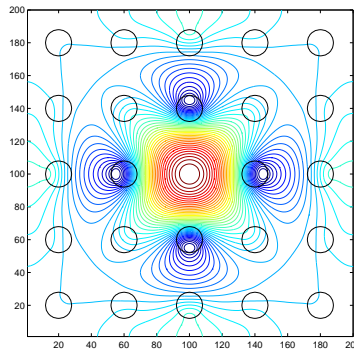


Fig. 5. The E_z field of a defect mode in a 2D square lattice with alumina rods in air using a 5x5 supercell with the center rod removed. The rods are displayed as black circles.

4. Conclusions

In conclusion, we have presented a FDFD method for photonic band gap calculations. This method is able to provide complete and accurate information about the band structure of a photonic crystal. The results of 2D TE/TM modes for two different geometries are compared with those obtained using plane wave method, and excellent agreement is achieved. By using a generalized coordinate system, various lattice geometries can be analyzed in the same manner.

Acknowledgments

The research at Old Dominion University is supported by NASA Langley Research Center through NASA-University Photonics Education and Research Consortium (NUPERC). We thank the reviewer for bringing references [11-13] to our attention.